









LMC6032, LMC6034 JAJS745D - NOVEMBER 1994 - REVISED FEBRUARY 2024

LMC603x CMOS デュアル オペアンプ

1 特長

- 2kΩ および 600Ω 負荷について動作を規定
- 高い電圧ゲイン: 126dB、2kΩ
- 低いオフセット電圧ドリフト: 2.3µV/°C
- 超低入力バイアス電流:40fA
- 入力同相範囲に **V-** を含む
- 標準の 5V および 15V 電源で動作
- I_O = 375µA / アンプ、V+ に非依存
- 低ノイズ: 22nV/√Hz
- スルーレート: 1.1V/µs
- TLC272 よりも性能が向上

2 アプリケーション

- ハイインピーダンスのバッファまたはプリアンプ
- 電流/電圧コンバータ
- 長時間積分器
- サンプル / ホールド回路
- 医療用計測装置

3 概要

デュアル LMC6032 およびクワッド LMC6034 (LMC603x)は、単一電源またはデュアル電源で動作する CMOS オペアンプです。デバイスの性能としては、グラン ドに達する入力同相範囲、低い入力バイアス電流、2kΩ および 600Ω などの現実的な負荷への高い電圧ゲインな どの特長を備えています。

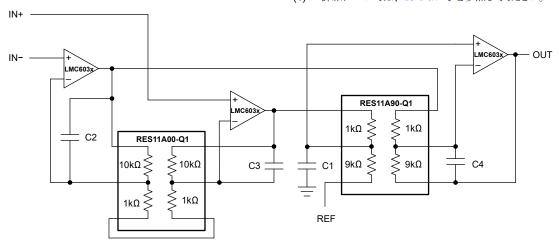
このチップは、TI の先進的な CMOS プロセスで製造され

より高性能な特性が必要な場合は、OPA928を参照してく ださい。

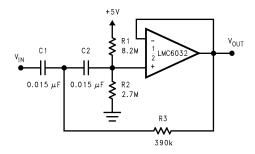
製品情報

部品番号	チャネル	パッケージ (1)
LMC6032	デュアル	D (SOIC, 8)
LIVICOUSE		P (PDIP、8)
LMC6034	クワッド	D (SOIC、14)
LIVICOUS	クンツr 	P (PDIP、14)

(1) 詳細については、セクション 9 を参照してください。



代表的なアプリケーション:RES11A を使った計装アンプ



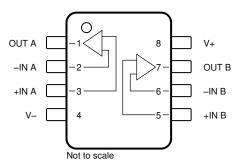
代表的なアプリケーション: 10Hz ハイパス フィルタ



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4 Pin Configuration and Functions

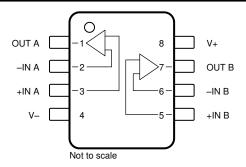


LMC6032 D Package, 8-Pin SOIC, and P Package, 8-Pin PDIP (Top View)

PIN **TYPE DESCRIPTION** NAME NO. +IN A 3 Input Noninverting input, channel A -IN A 2 Input Inverting input, channel A +IN B 5 Input Noninverting input, channel B –IN B 6 Input Inverting input, channel B OUT A Output Output, channel A 1 OUT B 7 Output Output, channel B V+ 8 Power Positive (highest) power supply Power Negative (lowest) power supply

表 4-1. Pin Functions: LMC6032





LMC6034 D Package, 14-Pin SOIC, and P Package, 14-Pin PDIP (Top View)

表 4-2. Pin Functions: LMC6034

PIN		TYPE	DESCRIPTION				
NAME	NO.	ITPE	DESCRIPTION				
+IN A	3	Input	Noninverting input, channel A				
+IN B	5	Input	Noninverting input, channel B				
+IN C	10	Input	Noninverting input, channel C				
+IN D	12	Input	Noninverting input, channel D				
–IN A	2	Input	nverting input, channel A				
–IN B	6	Input	Inverting input, channel B				
–IN C	9	Input	Inverting input, channel C				
–IN D	13	Input	Inverting input, channel D				
OUT A	1	Output	Output, channel A				
OUT B	7	Output	Output, channel B				
OUT C	8	Output	Output, channel C				
OUT D	14	Output	Output, channel D				
V+	4	Power	Positive (highest) power supply				
V-	11	Power	Negative (lowest) power supply				

English Data Sheet: SNOS609

5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)(1) (2)

		MIN	MAX	UNIT
Differential input voltage			±Supply voltage	V
Supply voltage, V _S = (V+) –	Single supply	0	16	V
(V–)	Dual supply		±8	V
Output abort aircuit	To V+		See ⁽²⁾	mΛ
Output short circuit	To V-		See ⁽³⁾	mA
Cinn al innut nin a	Voltage	(V-) - 0.3	(V+) + 0.3	V
Signal input pins	Current		±5	mA
Output pin current			±18	mA
Power supply pin	Current		35	mA
Power dissipation		See ⁽⁴⁾		
	Operating, T _A	-40	150	
Tomporatura	Junction, T _J		150	°C
Temperature	Storage, T _{stg}	-65	150	C
	Lead (soldering, 10 sec.)		260	

- (1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.
- (3) Do not connect output to V+, when V+ is greater than 13V or reliability will be adversely affected.
- (4) The maximum power dissipation is a function of $T_{J(max)}$, θ_{JA} , and T_A . The maximum allowable power dissipation at any ambient temperature is $P_D = (T_{J(max)} T_A) / \theta_{JA}$

5.2 ESD Ratings

			VALUE	UNIT
V _(ESD)	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 ⁽¹⁾	±1000	V

(1) JEDEC document JEP155 states that 500V HBM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)(1)

		MIN	NOM MAX	UNIT
Supply voltage \(\ = \lambda \tau \)	Single supply	4.75	15.5	V
Supply voltage, $V_S = (V+) - (V-)$	Dual supply	±2.375	±7.75	V
Specified temperature	·	-40	85	°C
Power dissipation		See ⁽²⁾		

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is intended to be functional, but do not ensure specific performance limits. For ensured specifications and test conditions, see the *Electrical Characteristics*. The ensured specifications apply only for the test conditions listed.
- (2) For operating at elevated temperatures the device must be derated based on the thermal resistance θ_{JA} with P_D = (T_J T_A) / θ_{JA}. All numbers apply for packages soldered directly into a printed circuit board.



5.4 Thermal Information LMC6032

		LMC		
	THERMAL METRIC ⁽¹⁾	D (SOIC)	P (PDIP)	UNIT
		8 PINS	8 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	165	101	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5.5 Thermal Information LMC6034

		LMC	6034	
	THERMAL METRIC ⁽¹⁾	D (SOIC)	P(PDIP)	UNIT
		14 PINS	14 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	115	85	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

5

Product Folder Links: LMC6032 LMC6034



5.6 Electrical Characteristics

at T_A = +25°C, V_S = 5V (V- = 0V), V_{CM} = 1.5V, V_{OUT} = V_S / 2, and R_L = 1M Ω connected to V_S / 2 (unless otherwise noted)

	PARAMETER	TEST COM	NDITIONS	MIN	TYP	MAX	UNIT	
OFFSET	VOLTAGE							
.,					±1	±9		
Vos	Input offset voltage	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$				±11	mV	
dV _{OS} /dT	Input offset voltage drift	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			±2.3		μV/°C	
		D 35 51/41/4 4451/		63	83			
PSRR	Power-supply rejection	Positive, 5V ≤ V+ ≤ 15V	$T_A = -40$ °C to +85°C	60				
	ratio	N (5)/ 4)// 4 40)/		74	94		dB	
		Negative, –5V ≤ V+ ≤ –10V	$T_A = -40$ °C to +85°C	70				
INPUT B	IAS CURRENT	1						
	land bing summed				±40		fA	
I _B	Input bias current	T _A = -40°C to +85°C				±200	pА	
					±10		fA	
I _{OS}	Input offset current	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$				±100	pА	
NOISE								
e _n	Input voltage noise density	f = 1kHz			22		nV/√Hz	
i _n	Input current noise density	f = 1kHz			4		fA/√Hz	
THD	Total harmonic distortion	f = 10kHz, G = -10V/V, R_L = 2kΩ, V	$V_{O} = 8V_{pp}, V_{S} = \pm 5V$		0.2		%	
INPUT V	OLTAGE	I.						
		To positive rail,		(V+) - 2.3	(V+) - 1.9			
	Common-mode voltage range	5V ≤ V _S ≤ 15V, CMRR > 50dB	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	(V+) - 2.6			.,	
V _{CM}		To negative rail,			(V-) - 0.4	(V-) - 0.1	V	
		5V ≤ V _S ≤ 15V, CMRR > 50dB	T _A = -40°C to +85°C			(V-)		
	Common-mode rejection	V _S = 15V,		63	83			
CMRR	ratio	0V < V _{CM} < 12V	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	60			dB	
INPUT IN	IPEDANCE	I.						
R _{IN}	Input resistance				> 1		TΩ	
OPEN-LO	DOP GAIN							
		Sourcing, V _S = 15V, V _{CM} = 7.5V,		200	2000			
		$7.5V < V_O < 11.5V, R_L = 2k\Omega$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	100				
		Sinking, V _S = 15V, V _{CM} = 7.5V,		90	500			
		$2.5V < V_O < 7.5V, R_L = 2k\Omega$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	40				
A _{OL}	Open-loop voltage gain	Sourcing, V _S = 15V, V _{CM} = 7.5V,		100	1000		V/mV	
		$7.5V < V_O < 11.5V, R_L = 600\Omega$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	75				
		Sinking, V _S = 15V, V _{CM} = 7.5V,		50	250			
		$2.5V < V_O < 7.5V, R_L = 600\Omega$	T _A = -40°C to +85°C	20			1	
FREQUE	NCY RESPONSE	1						
GBW	Gain bandwidth product				1.4		MHz	
				0.8	1.1			
SR	Slew rate ⁽¹⁾	V _S = 15V, 10V step	T _A = -40°C to +85°C	0.4			V/µs	
θ_{m}	Phase margin				50		۰	
		Dual and quad channel, V _S = 15V,	$R_L = 10k\Omega$ to 7.5V, $f = 1kHz$.		400			
	Crosstalk	$V_0 = 13V_{pp}$	- · , · - ,		130		dB	

5.6 Electrical Characteristics (続き)

at T_A = +25°C, V_S = 5V (V- = 0V), V_{CM} = 1.5V, V_{OUT} = V_S / 2, and R_L = 1M Ω connected to V_S / 2 (unless otherwise noted)

	PARAMETER	TEST CONI	DITIONS	MIN	TYP	MAX	UNIT	
OUTPUT								
		Positive rail		4.20	4.87			
		$V_S = 5V$, $R_L = 2k\Omega$ to mid-supply	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	4.00				
		Negative rail			0.10	0.25		
		$V_S = 5V$, $R_L = 2k\Omega$ to mid-supply	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			0.35		
		Positive rail		4.00	4.61			
		$V_S = 5V$, $R_L = 600\Omega$ to mid-supply	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	3.80				
		Negative rail			0.30	0.63		
\ /	Voltage output owing	$V_S = 5V$, $R_L = 600\Omega$ to mid-supply	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			0.75	V	
Vo	Voltage output swing	Positive rail		13.50	14.63		V	
		$V_S = 15V$, $R_L = 2k\Omega$ to mid-supply	T _A = -40°C to +85°C	13.00				
		Negative rail			0.26	0.45	mA	
		$V_S = 15V$, $R_L = 2k\Omega$ to mid-supply	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$			0.55		
		Positive rail		12.50	13.90			
		V_S = 15V, R_L = 600 Ω to mid-supply	T _A = -40°C to +85°C	12.00				
		Negative rail			0.79	1.45		
		$V_S = 15V$, $R_L = 600\Omega$ to mid-supply	T _A = -40°C to +85°C			1.75		
		Sourcing		13	22			
		$V_S = 5V$, $V_O = 0V$	T _A = -40°C to +85°C	9				
		Sinking		13	21			
ı	Chart aircuit aurrant	$V_S = 5V$, $V_O = 5V$	T _A = -40°C to +85°C	9				
I _{SC}	Short-circuit current	Sourcing		23	40			
		$V_S = 15\overline{V}, V_O = 0V$	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$	15				
		Sinking		23	39			
		$V_S = 15V, V_O = 13V^{(2)}$	T _A = -40°C to +85°C	15				
POWER	SUPPLY		1					
			LMC6032		375	800		
ı	Quiescent current per	V = 4.5V	LMC6032, T _A = -40°C to +85°C			950	μΑ	
IQ	amplifier	V _O = 1.5V	LMC6034		375	675		
			LMC6034, T _A = -40°C to +85°C			750		
						750		

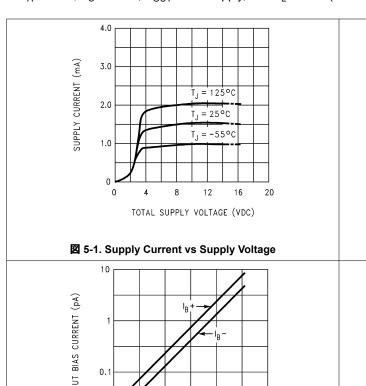
⁽¹⁾ Specification limit established from device population bench system measurements across multiple lots. Number specified is the slower of either the positive or negative slew rates.

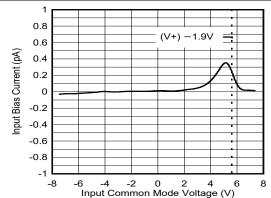
⁽²⁾ Do not connect output to V+, when V+ is greater than 13V or reliability can be adversely affected.



Typical Characteristics

at T_A = 25°C, V_S = ±7.5V, V_{OUT} = mid-supply, and R_L > 1M Ω (unless otherwise noted)





(V+) - 1.9V

6 -4 -2 0 2 4 6 Input Common Mode Voltage (V)

図 5-2. Offset Voltage vs Input Common-Mode Voltage

6

-3

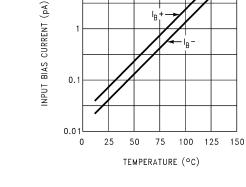
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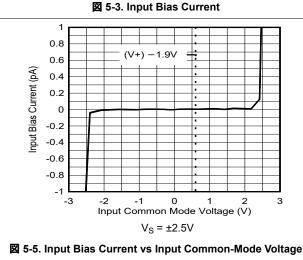
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-6

Input Offset Voltage (mV)







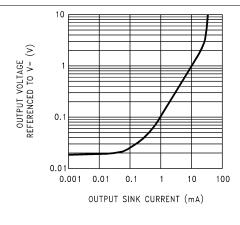
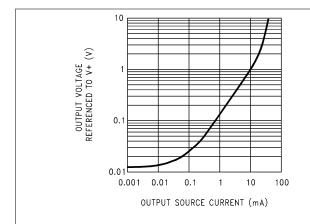


図 5-6. Output Characteristics Current Sinking



Typical Characteristics (continued)

at T_A = 25°C, V_S = ±7.5V, V_{OUT} = mid-supply, and R_L > 1M Ω (unless otherwise noted)



☑ 5-7. Output Characteristics Current Sourcing

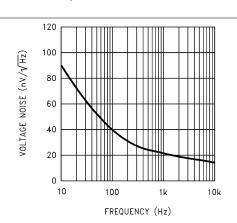


図 5-8. Input Voltage Noise vs Frequency

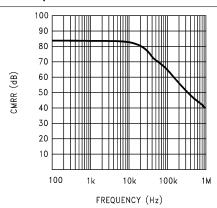
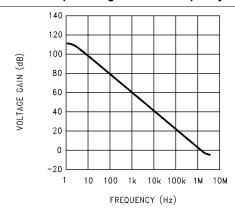
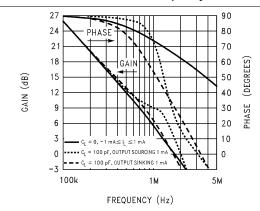


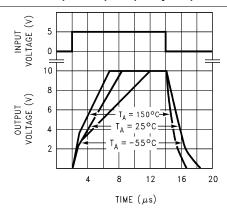
図 5-9. CMRR vs Frequency



☑ 5-10. Open-Loop Frequency Response



☑ 5-11. Frequency Response vs Capacitive Load

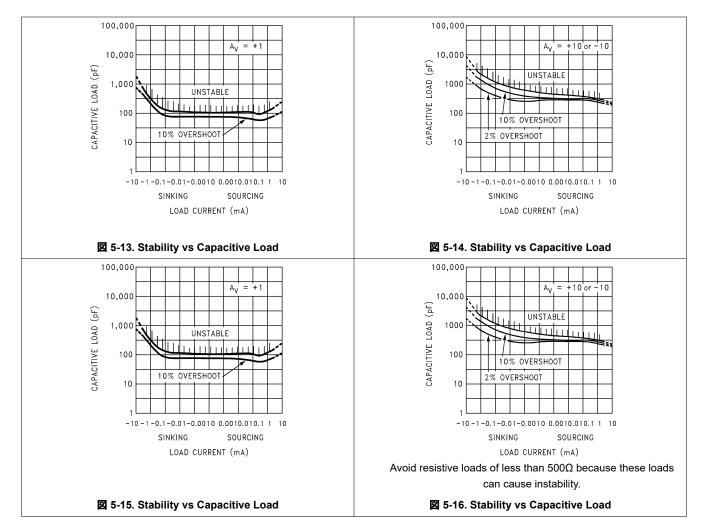


☑ 5-12. Noninverting Large-Signal Pulse Response



Typical Characteristics (continued)

at T_A = 25°C, V_S = ±7.5V, V_{OUT} = mid-supply, and R_L > 1M Ω (unless otherwise noted)





6 Application and Implementation

注

以下のアプリケーション情報は、TIの製品仕様に含まれるものではなく、TIではその正確性または完全性を保証いたしません。個々の目的に対する製品の適合性については、お客様の責任で判断していただくことになります。お客様は自身の設計実装を検証しテストすることで、システムの機能を確認する必要があります。

6.1 Application Information

6.1.1 Amplifier Topology

The topology chosen for the LMC603x, shown in 🗵 6-1, is unconventional compared to general-purpose op amps. The LMC603x incorporates novel op-amp design that enables a wide input common-mode range and rail to rail output swing even when driving a large load. The input common-mode range includes ground, making the LMC603x an excellent choice for single-supply applications. While the LMC603x supports both a wide supply and common-mode voltage range, large input common-mode voltage can cause a degradation of input bias current performance.

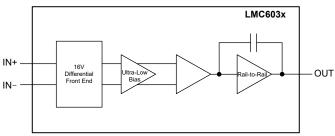


図 6-1. LMC603x Circuit Topology (Each Amplifier)

6.1.2 Compensating Input Capacitance

The high input resistance of the LMC603x op amps allows the use of large feedback and source resistor values without losing gain accuracy due to loading. However, the circuit can be especially sensitive to the printed circuit board (PCB) layout when these large-value resistors are used.

Every amplifier has some capacitance between each input and ac ground, and also some differential capacitance between the inputs. When the feedback network around an amplifier is resistive, this input capacitance (along with any additional capacitance due to circuit board traces, the socket, and so on) and the feedback resistors create a pole in the feedback path. In \boxtimes 6-2, the frequency of this pole is:

$$f_p = \frac{1}{2\pi C_S R_P} \tag{1}$$

where C_S is the total capacitance at the inverting input, including amplifier input capacitance and any stray capacitance from the IC socket (if one is used), circuit board traces, and so on, and R_P is the parallel combination of R_F and R_{IN} . This formula, as well as all the following formulas, apply to inverting and noninverting op-amp configurations.

When the feedback resistors are smaller than a few $k\Omega$, the frequency of the feedback pole can be quite high, since C_S is generally less than 10pF. If the frequency of the feedback pole is much greater than the *ideal* closed-loop bandwidth (the nominal closed-loop bandwidth in the absence of C_S), the pole has a negligible effect on stability, as only a small amount of phase shift is added.

However, if the feedback pole is less than approximately 6 to 10 times the *ideal* –3dB frequency, add a feedback capacitor, C_F, between the output and the inverting input of the op amp. This condition can also be stated in terms of the amplifier low-frequency noise gain: To maintain stability, a feedback capacitor is probably needed if:

$$\left(\frac{R_F}{R_{IN}} + 1\right) \le \sqrt{6 \times 2\pi \times GBW \times R_F \times C_S} \tag{2}$$

where

- $\left(\frac{R_F}{R_{IN}}+1\right)$ is the amplifier low-frequency noise gain.
- · GBW is the amplifier gain bandwidth product.

An amplifier low-frequency noise gain is represented by the following formula:

$$\left(\frac{R_F}{R_{IN}} + 1\right) \tag{3}$$

regardless of whether the amplifier is being used in an inverting or noninverting mode. A feedback capacitor is more likely to be needed when the noise gain is low, the feedback resistor is large. or both.

If the previous condition is met (indicating a feedback capacitor is probably be needed), and the noise gain is large enough that $\left(\frac{R_F}{R_{IN}}+1\right) \geq 2\sqrt{GBW \times R_F \times C_S}$, the following value of feedback capacitor is recommended:

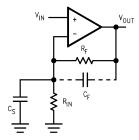
$$C_F = \frac{C_S}{2\left(\frac{R_F}{R_{IN}} + 1\right)} \tag{4}$$

If $\left(\frac{R_F}{R_{IN}}+1\right) < 2\sqrt{GBW \times R_F \times C_S}$, the feedback capacitor is:

$$C_F = \sqrt{\frac{C_S}{GBW \times R_F}} \tag{5}$$

These capacitor values are usually significantly smaller than those given by the older, more conservative formula:

$$C_F = \frac{C_S R_{IN}}{R_F} \tag{6}$$



 C_S consists of the amplifier input capacitance plus any stray capacitance from the circuit board and socket. C_F compensates for the pole caused by C_S and the feedback resistor.

図 6-2. General Operational Amplifier Circuit

Using the smaller capacitors give much higher bandwidth with little degradation of transient response. Using a somewhat larger feedback capacitor can be necessary in any of the above cases to allow for unexpected stray capacitance, or to tolerate additional phase shifts in the loop, or excessive capacitive load, or to decrease the noise or bandwidth, or simply because the particular circuit implementation needs more feedback capacitance to



be sufficiently stable. For example, a PCB stray capacitance can be larger or smaller than the breadboard capacitance, so the actual preferred value for C_F can be different from the one estimated using the breadboard. In most cases, check the value of C_F on the actual circuit, starting with the computed value.

6.1.3 Capacitive Load Tolerance

Like many other op amps, the LMC603x can oscillate when applied a load that appears capacitive. The threshold of oscillation varies both with load and circuit gain. The configuration most sensitive to oscillation is a unity-gain follower. See also セクション Typical Characteristics.

The load capacitance interacts with the op amp output resistance to create an additional pole. If this pole frequency is sufficiently low, the op amp phase margin is degraded so that the amplifier is no longer stable at low gains. \boxtimes 6-3 shows that the addition of a small resistor (50 Ω to 100 Ω) in series with the op amp output, and a capacitor (5pF to 10pF) from inverting input to output pins, returns the phase margin to a safe value without interfering with lower-frequency circuit operation. Thus, larger values of capacitance can be tolerated without oscillation. In all cases, the output can ring heavily when the load capacitance is near the threshold for oscillation.

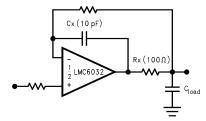


図 6-3. Rx, Cx Improve Capacitive Load Tolerance

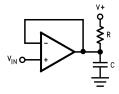


図 6-4. Compensating for Large Capacitive Loads with a Pullup Resistor

6.1.4 Bias Current Testing

The test method of 🗵 6-5 is appropriate for bench-testing bias current with reasonable accuracy. To understand the circuit operation, first close switch S2 momentarily. When S2 is opened, then:

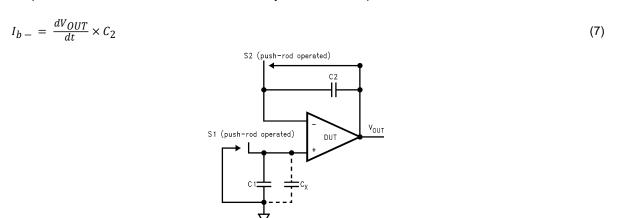


図 6-5. Simple Input Bias Current Test Circuit

A recommended capacitor for C2 is a 5pF or 10pF silver mica, NPO ceramic, or air-dielectric. When determining the magnitude of I_b -, the leakage of the capacitor and socket must be taken into account. Leave switch S2 shorted most of the time, or else the dielectric absorption of the capacitor C2 can cause errors.

Similarly, if S1 is shorted momentarily (while leaving S2 shorted), then:

$$I_{b+} = \frac{dV_{OUT}}{dt} \times (C_1 + C_x) \tag{8}$$

where $C_{\boldsymbol{x}}$ is the stray capacitance at the + input.

6.2 Typical Applications

Typical Single-Supply Applications

Additional single-supply applications ideas are found in the LM358 data sheet. The LMC603x is pin-for-pin compatible with the LM358 and offers greater bandwidth and input resistance over the LM358. These features can improve the performance of many existing single-supply applications. Be aware, however, the supply voltage range of the LMC603x is smaller than that of the LM358.

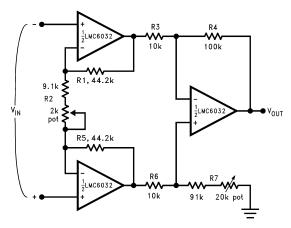


図 6-6. Instrumentation Amplifier

$$\frac{V_{OUT}}{V_{IN}} = \frac{R2 + 2R1}{R2} \times \frac{R4}{R3}$$

If R1 = R5, R3 = R6, and R4 = R7, then A_V = 100 for circuit shown.

Use low-drift resistors for good CMRR performance over temperature. Matching of R3 to R6 and R4 to R7 affects CMRR. Gain is adjusted through R2. CMRR is adjusted through R7. An improved circuit can be designed using the RES11A-Q1, low-drift, precision, matched resistor pairs. ☒ 6-7 shows how a precise gain of 99 is easily implemented. The capacitors are optional and are be used to improve noise performance, if needed.

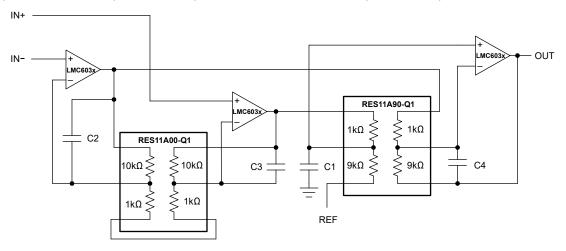
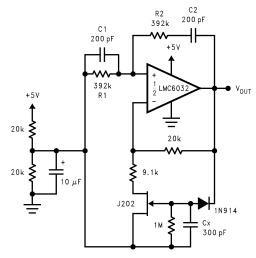


図 6-7. Improved Instrumentation Amplifier With RES11A





Oscillator frequency is determined by R1, R2, C1, and C2:

 $f_{OSC} = 1/2\pi RC$

where R = R1 = R2 and C = C1 = C2.

図 6-8. Sine-Wave Oscillator

This circuit, as shown, oscillates at 2.0kHz with a peak-to-peak output swing of 4.0V.

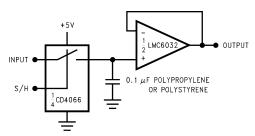
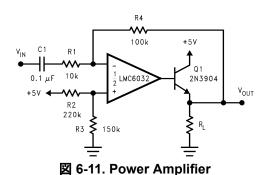


図 6-9. Low-Leakage Sample-and-Hold



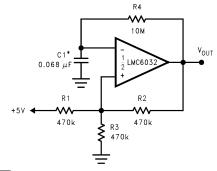
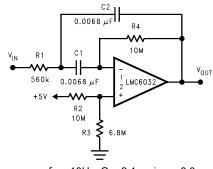


図 6-10. 1Hz Square-Wave Oscillator



 $f_{O} = 10$ Hz, Q = 2.1, gain = -8.8

図 6-12. 10Hz Bandpass Filter



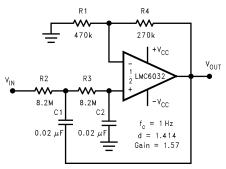
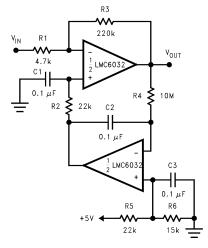


図 6-13. 1Hz Low-Pass Filter (Maximally Flat, Dual Supply Only)

f_c = 10Hz, d = 0.895, gain = 1, 2dB pass-band ripple

☑ 6-14. 10Hz High-Pass Filter



Gain = -46.8 Output offset voltage reduced to the level of the input offset voltage of the bottom amplifier (typically 1mV).

図 6-15. High-Gain Amplifier With Offset Voltage Reduction

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Product Folder Links: LMC6032 LMC6034

6.3 Layout

6.3.1 Layout Guidelines

6.3.1.1 Printed Circuit Board Layout for High-Impedance Work

Generally, any circuit that operates with less than 1000pA of leakage current requires special layout of the printed circuit board (PCB). To take advantage of the ultra-low bias current of the LMC603x, typically less than 40fA, an excellent layout is essential. Fortunately, the techniques for obtaining low leakages are quite simple. Foremost, do not ignore the surface leakage of the PCB, even though the leakage can sometimes appear acceptably low, because under conditions of high humidity or dust or contamination, the surface leakage can be appreciable.

To minimize the effect of any surface leakage, lay out a ring of foil completely surrounding the LMC603x inputs and the terminals of capacitors, diodes, conductors, resistors, relay terminals, and so on, connected to the op amp inputs. See \boxtimes 6-16. To have a significant effect, place guard rings on both the top and bottom of the PCB. This PCB foil must then be connected to a voltage which is at the same voltage as the amplifier inputs, since no leakage current can flow between two points at the same potential. For example, a PCB trace-to-pad resistance of $10^{12}\Omega$, which is normally considered a very large resistance, can leak 5pA if the trace were a 5V bus adjacent to the pad of an input. This causes a 100 times degradation from the LMC603x actual performance. However, if a guard ring is held within 5mV of the inputs, then even a resistance of $10^{11}\Omega$ causes only 50fA of leakage current, or perhaps a minor (2:1) degradation of the amplifier performance. See \boxtimes 6-17, \boxtimes 6-18, \boxtimes 6-19 for typical connections of guard rings for standard op amp configurations. If both inputs are active and at high impedance, the guard can be tied to ground and still provide some protection; see \boxtimes 6-20.

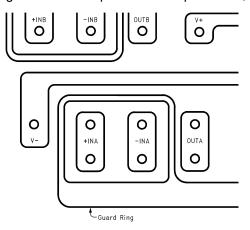


図 6-16. Example of Guard Ring in PCB Layout

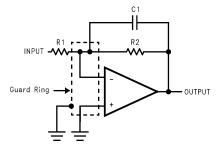
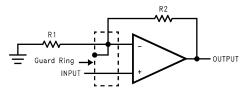


図 6-17. Inverting Amplifier Guard-Ring Connections

Product Folder Links: LMC6032 LMC6034





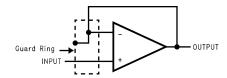


図 6-18. Noninverting Amplifier Guard-Ring Connections

図 6-19. Follower Guard-Ring Connections

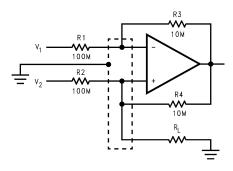
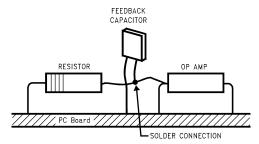


図 6-20. Howland Current-Pump Guard-Ring Connections

Be aware that when laying out a PCB for the sake of just a few circuits is inappropriate, there is another technique which is even better than a guard ring on a PCB. Do not insert the amplifier input pin into the board at all, but bend the pin up in the air and use only air as an insulator. Air is an excellent insulator. In this case you forgo some of the advantages of PCB construction, but the advantages of air are sometimes well worth the effort of using point-to-point up-in-the-air wiring. See \boxtimes 6-21.



Input pins are lifted out of PCB and soldered directly to components. All other pins connected to the PCB.

図 6-21. Air Wiring



7 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

7.1 ドキュメントの更新通知を受け取る方法

ドキュメントの更新についての通知を受け取るには、www.tij.co.jp のデバイス製品フォルダを開いてください。[通知] をクリックして登録すると、変更されたすべての製品情報に関するダイジェストを毎週受け取ることができます。 変更の詳細については、改訂されたドキュメントに含まれている改訂履歴をご覧ください。

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7.4 用語集

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8 Revision History

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

С	hanges from Revision C (March 2013) to Revision D (February 2024)	Page
•	LMC6034 および関連情報を追加	1
•	「特長」の電気的特性に合わせて Io を 400µA から 375µA に変更	1
•	「特長」の 高い電圧ゲインを 12dB から 126dB に変更 (誤字)	1
•	「特長」の低ノイズを追加し、低歪みを削除	
•	「概要」に 高性能 OPA928 の参照を追加	1
•	Added Pin Configuration and Functions	
•	Added Thermal Information	_
•	Changed parameter names to conform with new standards in <i>Electrical Characteristics</i>	<mark>6</mark>
•	Changed input current noise specification from 0.0002pA/ $\sqrt{\text{Hz}}$ to 4fA/ $\sqrt{\text{Hz}}$ in <i>Electrical Characteristics</i>	6
•	Changed total harmonic distortion specification from 0.01% to 0.2% in Electrical Characteristics	6
•	Updated conditions in the header of Typical Characteristics	8
•	Added input offset voltage vs common mode voltage and input bias current vs common mode voltage	
•	Updated description and circuit topology diagram in Amplifier Topology	
•	Added new instrumentation amplifier circuit using the RES11A to Typical Applications	

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Changes from Revision B (March 2013) to Revision C (March 2013)

Page

9 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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Product Folder Links: LMC6032 LMC6034

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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
LMC6032IMX/NOPB	ACTIVE	SOIC	D	8	2500	RoHS & Green	(6) SN	Level-1-260C-UNLIM	-40 to 85	LMC60 32IM	Samples
LMC6032IN/NOPB	ACTIVE	PDIP	Р	8	40	RoHS & Green	NIPDAU	Level-1-NA-UNLIM	-40 to 85	LMC 6032IN	Samples
LMC6034IMX/NOPB	ACTIVE	SOIC	D	14	2500	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 85	LMC6034IM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

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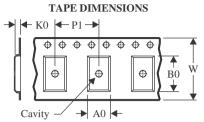
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

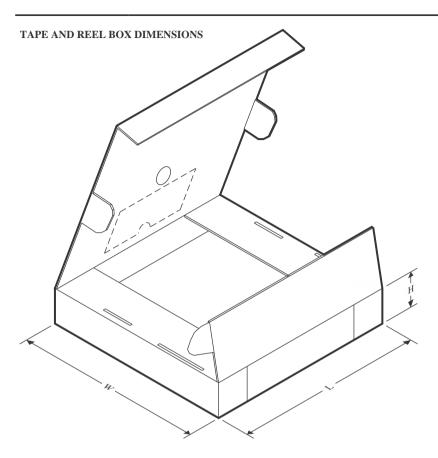
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
LMC6032IMX/NOPB	SOIC	D	8	2500	330.0	12.4	6.5	5.4	2.0	8.0	12.0	Q1
LMC6034IMX/NOPB	SOIC	D	14	2500	330.0	16.4	6.5	9.35	2.3	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
LMC6032IMX/NOPB	SOIC	D	8	2500	367.0	367.0	35.0
LMC6034IMX/NOPB	SOIC	D	14	2500	356.0	356.0	35.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
LMC6032IN/NOPB	Р	PDIP	8	40	506	13.97	11230	4.32
LMC6032IN/NOPB	Р	PDIP	8	40	502	14	11938	4.32

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.





SMALL OUTLINE INTEGRATED CIRCUIT



- 1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
- 2. This drawing is subject to change without notice.
- 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
- 4. This dimension does not include interlead flash.
- 5. Reference JEDEC registration MS-012, variation AA.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE INTEGRATED CIRCUIT



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



P (R-PDIP-T8)

PLASTIC DUAL-IN-LINE PACKAGE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MS-001 variation BA.



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